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TECHNOLOGY CENTER 2800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: Jack O. Chu et al. / : Date: April 1, 2003  
Serial No.: 09/989,770 / : Group Art Unit: 2815  
Confirmation No.: 2335 / : Examiner: Jesse A. Fenty  
Filed: November 20, 2001 : Attorney Docket No.: YOR919980460US2  
For: High Speed Composite p-Channel Si/SiGe Heterostructure for Field Effect Devices

Commissioner for Patents  
Initial Patent Examination Division  
Washington, D.C. 20231

#8  
Election  
J.W. Cimler  
4/16/03

Response to Restriction Requirement

Sir:

In response to the Requirement for Restriction dated December 18, 2002,  
Applicants elect Group II, Claims 43-72, drawn to a method of making semiconductor  
devices, classified in class 438, subclass 1+.

Group I, Claim 42, drawn to a semiconductor device, classified in class 257,  
subclass 19 is withdrawn from further prosecution and non-elected.

Further favorable action and allowance of the claims is earnestly requested.

Respectfully submitted,  
Attorney for the Applicant(s)

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